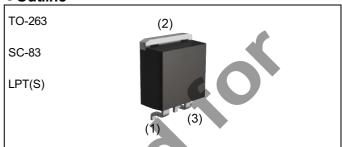
Nch 600V 20A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.28Ω
I _D	±20A
P_D	304W

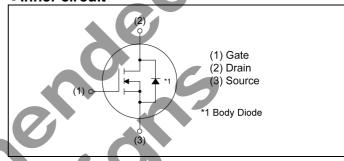
●Outline



Features

- 1) Fast reverse recovery time (trr).
- 2) Low on-resistance.
- 3) Fast switching speed.
- 4) Gate-source voltage (V_{GSS}) guaranteed to be $\pm 30V$.
- 5) Drive circuits can be simple.
- 6) Pb-free lead plating; RoHS compliant

Inner circuit



Packaging specifications

- 5.5.1.5.3	,	
	Packing	Embossed Tape
	Reel size (mm)	330
Type	Tape width (mm)	24
	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	R6020FNJ

Application

Switching Power Supply

● Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

Paramete		Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	600	V
Continuous drain ourrant	T _C = 25°C	I _D *1	±20	А
Continuous drain current	T _C = 100°C	I _D *1	±9.6	А
Pulsed drain current	I _{DP} *2	±80	А	
Gate - Source voltage		V_{GSS}	±30	V
Avalanche current, single pulse		I _{AS} *3	10	А
Avalanche energy, single pulse	E _{AS} *3	26.7	mJ	
Avalanche energy, repetitive		E _{AR} *4	3.5	mJ
Power dissipation (T _c = 25°C)		P _D	304	W
Junction temperature		T _j	150	°C
Operating junction and storage to	T _{stg}	-55 to +150	°C	
Reverse diode dv/dt		dv/dt	15	V/ns

Absolute maximum ratings

Parameter	Symbol	Conditions	Values	Unit
Drain - Source voltage slope	d∨/dt	$V_{DS} = 480V, I_{D} = 20A$ $T_{j} = 125^{\circ}C$	50	V/ns

●Thermal resistance

Parameter	Symbol	Values			Unit
	- Cymson	Min.	Тур.	Max.	01111
Thermal resistance, junction - case	R _{thJC}	-	-	0.41	°C/W
Thermal resistance, junction - ambient	R _{thJA}		1	80	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}		-	265	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol Conditions		Values		Unit	
r ai ai i letei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DS\$}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	ı	V
Drain - Source avalanche breakdown voltage	V _{(BR)DS}	$V_{GS} = 0V, I_D = 10A$	-	700	-	V
		$V_{DS} = 600V, V_{GS} = 0V$				
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	1	100	μΑ
didin odnon		T _j = 125°C	-	-	10	
Gate - Source leakage current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	3	-	5	V
		V _{GS} = 10V, I _D = 10A				
Static drain - source on - state resistance	R _{DS(on)} *6	T _j = 25°C	-	0.22	0.28	Ω
on state regionality		T _j = 125°C	-	0.44	-	
Gate resistance	R_{G}	f = 1MHz, open drain	-	13.4	-	Ω

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● Electrical characteristics (T_a = 25°C)

Davanatas Canditiana		Conditions		Values		Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} *6	V _{DS} = 10V, I _D = 10A	7.0	13	_	S
Input capacitance	C _{iss}	V _{GS} = 0V	ı	2350		
Output capacitance	C _{oss}	V _{DS} = 25V	-	1450)	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	40	_	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V,		69.8	-	ړ
Effective output capacitance, time related	C _{o(tr)}	V _{DS} = 0V to 480V		260	-	pF
Turn - on delay time	t _{d(on)} *6	V _{DD} ≈ 300V, V _{GS} = 10V	-	75	-	
Rise time	t _r *6	I _D = 10A		80	-	120
Turn - off delay time	t _{d(off)} *6	$R_L \simeq 30\Omega$		210	420	ns
Fall time	t _f *6	$R_G = 10\Omega$		40	80	

● Gate charge characteristics (T_a = 25°C)

Parameter	Symbol	Symbol Conditions -		Values		
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	$Q_g^{\star 6}$	V _{DD} ≃ 300V	-	60	1	
Gate - Source charge	Q_{gs}^{*6}	I _D = 20A	-	15	1	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	25	1	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 300V$, $I_D = 20A$	-	6.6	-	V

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw≤10μs, Duty cycle≤1%

^{*3} L \simeq 500 μ H, V_{DD} = 50V, R_G = 25 Ω , starting T_j = 25°C

^{*4} L $^{\sim}$ 500 μ H, V $_{DD}$ = 50V, R $_{G}$ = 25 Ω , starting T $_{j}$ = 25 $^{\circ}$ C, f = 10kHz

^{*5} Reference measurement circuits Fig.5-1.

^{*6} Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Darameter	Cymbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I _S *1	T - 25°C	-	-	20	Α
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	80	А
Forward voltage	V_{SD}^{*6}	$V_{GS} = 0V, I_{S} = 20A$	-	-	1.5	V
Reverse recovery time	t _{rr} *6		-	105	-	ns
Reverse recovery charge	Q _{rr} *6	I _S = 20A di/dt = 100A/µs		0.32	-	μC
Peak reverse recovery current	I _{rrm} *6	αναι 100/ γμο		8.0	-	Α
Peak rate of fall of reverse recovery current	di _{rr} /dt	T _j = 25°C)-	1100	-	A/µs

● Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.0462	
R _{th2}	0.17	K/W
R _{th3}	0.6	

Symbol	Value	Unit
C _{th1}	0.00308	
C _{th2}	0.0118	Ws/K
C _{th3}	0.232	

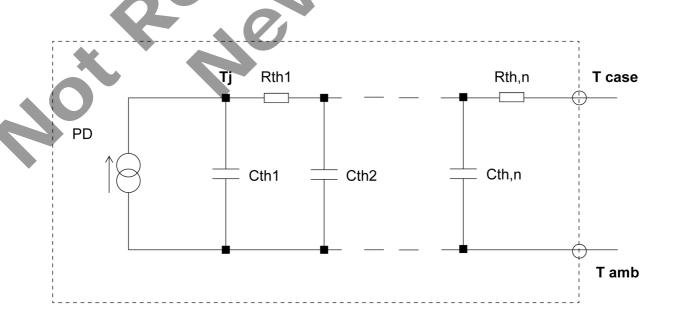


Fig.1 Power Dissipation Derating Curve

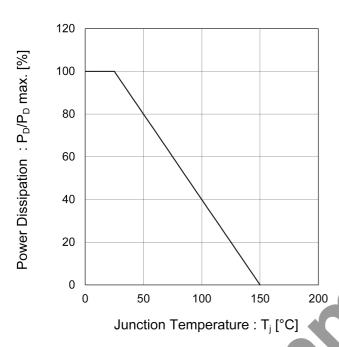


Fig.2 Maximum Safe Operating Area

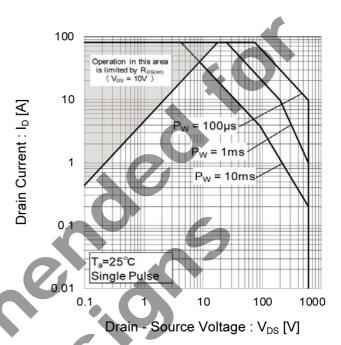
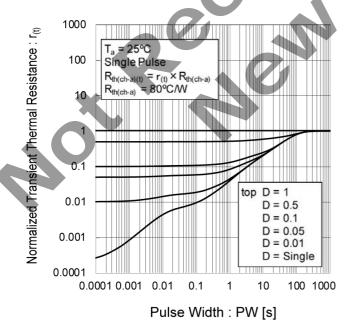


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



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Avalanche Current : IAR [A]

• Electrical characteristic curves

Fig.4 Avalanche Current vs. Inductive Load

14 $T_a = 25^{\circ}C$ $V_{DD} = 50V$, $R_G = 25\Omega$ $V_{GF} = 10V$, $V_{GR} = 0V$ 10 8
6
4
2
0
0.01 0.1 1 10 100

Coil Inductance : L [mH]

Fig.5 Avalanche Power Losses

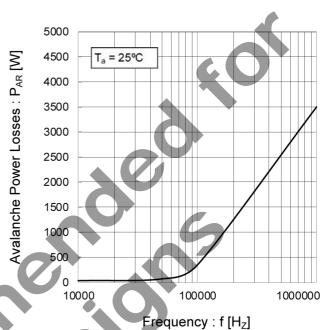


Fig.6 Avalanche Energy Derating Curve vs. Junction Temperature

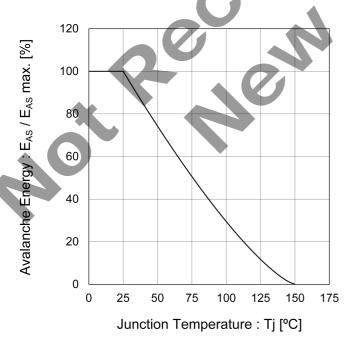
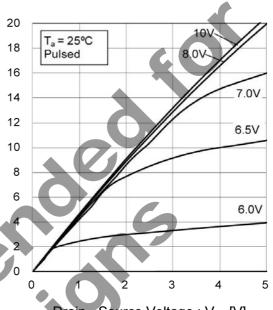


Fig.7 Typical Output Characteristics(I)

20 T_a = 25°C 18 Pulsed 16 6.5V Drain Current : I_D [A] 14 12 10 8 6.0V 6 4 2 0 0 Drain - Source Voltage : $V_{DS}[V]$

Fig.8 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.9 Tj = 150°C Typical Output Characteristics (I)

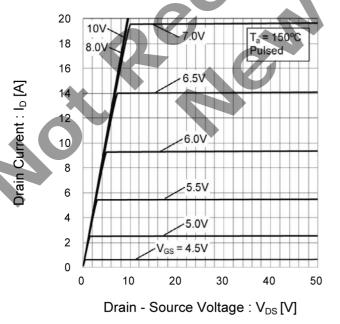
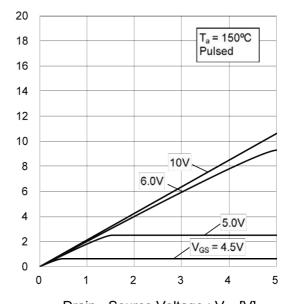


Fig.10 Tj = 150°C Typical Output Characteristics (II)



Drain Current : I_D [A]

Fig.11 Breakdown Voltage vs. Junction Temperature

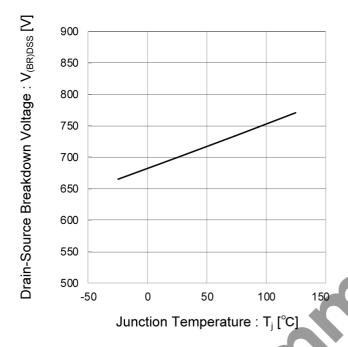


Fig.12 Typical Transfer Characteristics

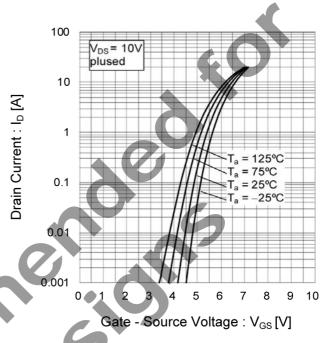


Fig.13 Gate Threshold Voltage vs Junction Temperature

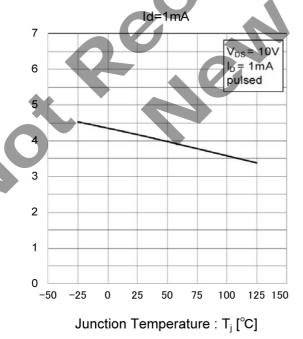
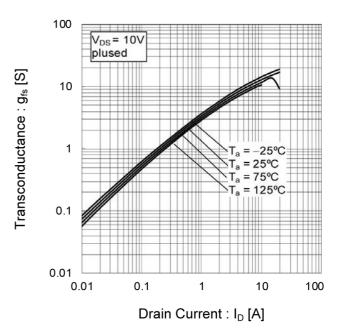


Fig.14 Transconductance vs. Drain Current



Gate Threshold Voltage: V_{GS(th)} [V]

Fig.15 Static Drain - Source On - State Resistance vs. Gate Source Voltage

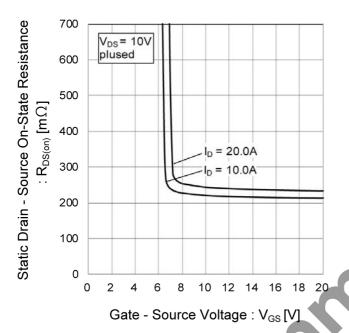


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature

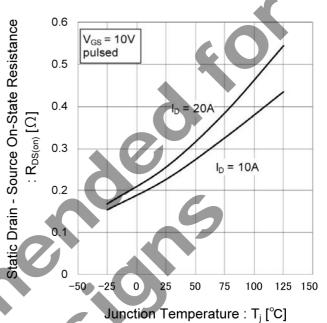


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current

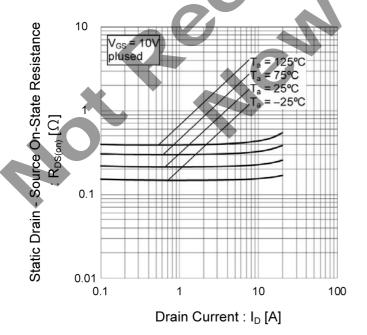


Fig.18 Typical Capacitance vs. Drain - Source Voltage

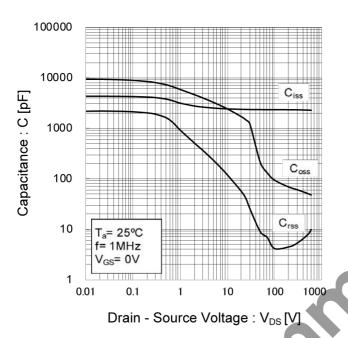


Fig.19 Coss Stored Energy

Coss Stored Energy : E $_{
m oss}$ [μ J]

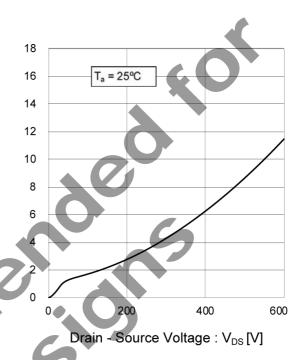


Fig.20 Switching Characteristics

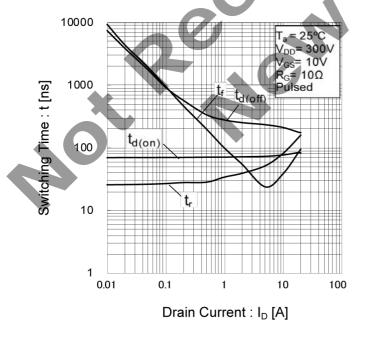
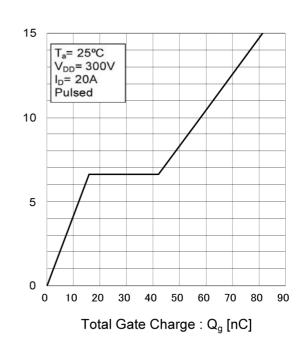


Fig.21 Dynamic Input Characteristics



Gate - Source Voltage : $V_{GS}\left[V\right]$

Inverse Diode Forward Current : Is [A]

Electrical characteristic curves

Fig.22 Inverse Diode Forward Current vs. Source - Drain Voltage

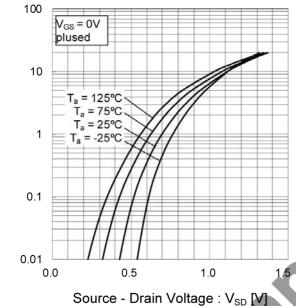
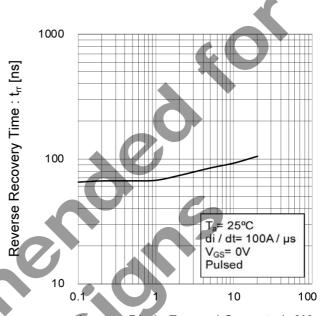


Fig.23 Reverse Recovery Time vs. Inverse Diode Forward Current



Inverse Diode Forward Current : Is [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

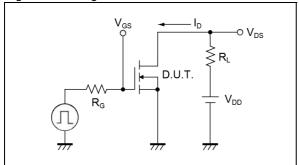


Fig.2-1 Gate Charge Measurement Circuit

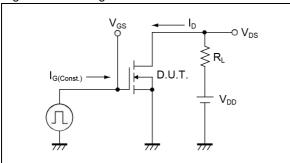


Fig.3-1 Avalanche Measurement Circuit

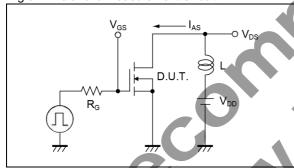


Fig.4-1 dv/dt Measurement Circuit

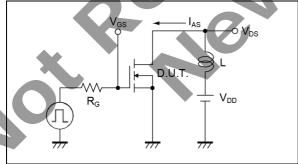


Fig.5-1 di/dt Measurement Circuit

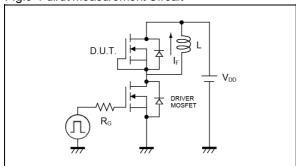


Fig.1-2 Switching Waveforms

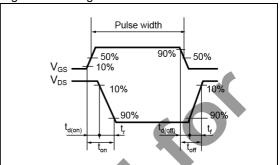


Fig.2-2 Gate Charge Waveform

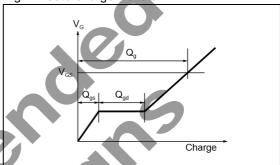


Fig.3-2 Avalanche Waveform

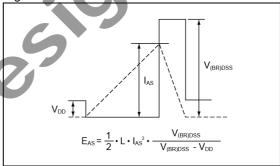


Fig.4-2 dv/dt Waveform

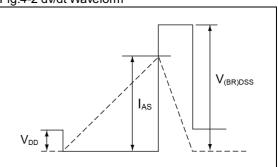
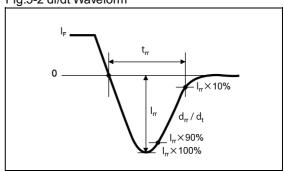
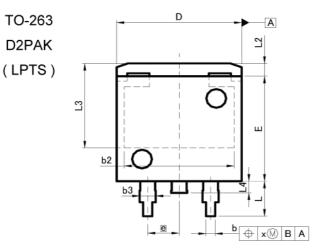
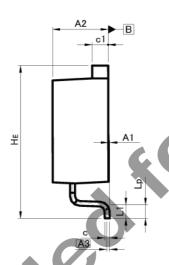


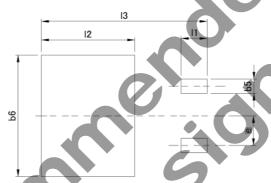
Fig.5-2 di/dt Waveform



Dimensions







Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.30	0.000	0.012
A2	4.30	4.70	0.169	0.185
A3	0.	25	0.0	10
b	0.68	0.98	0.027	0.039
62	8.	90	0.3	350
b3	1.14	1.44	0.045	0.057
C	0.30	0.60	0.012	0.024
c1	1.10	1.50	0.043	0.059
U	9.80	10.40	0.386	0.409
E	8.80	9.20	0.346	0.362
е	2.	54	0.1	00
HE	12.80	13.40	0.504	0.528
L	2.70	3.30	0.106	0.130
	1.20		0.047	
L2	1.10		0.043	
L3	7.	25	0.2	285
L4	1.	00	0.0	39
Lp	0.90	1.50	0.035	0.059
X		0.25	_	0.010

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b5	=:	1.23	-	0.049
b6	= 0	10.40		0.409
11	<u>22</u> 8	2.10	, 12	0.083
12	 .	7.55	1.00	0.297
13	_	13.40	-	0.528

Dimension in mm/inches

Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSII	CLASS II b	CLASSIII
CLASSIV		CLASSⅢ	CLASSIII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power, exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

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Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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